

TOSHIBA TRANSISTOR SILICON NPN EPITAXIAL TYPE (PCT PROCESS)

2SC4738F

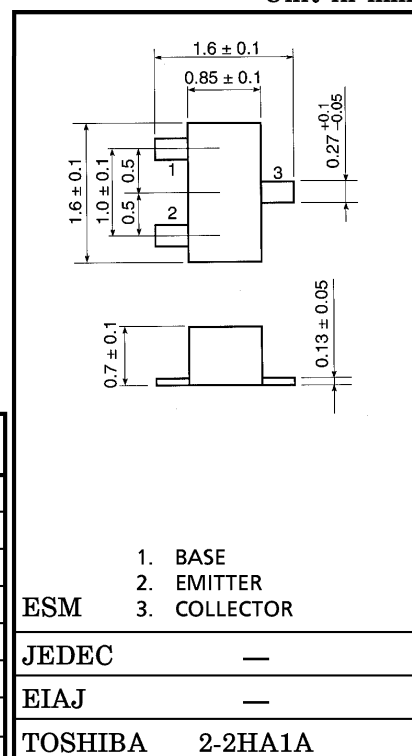
AUDIO FREQUENCY GENERAL PURPOSE AMPLIFIER APPLICATIONS

Unit in mm

- High Voltage and High Current
: $V_{CEO} = 50\text{ V}$, $I_C = 150\text{ mA}$ (Max.)
- Excellent h_{FE} Linearity
: $h_{FE} (I_C = 0.1\text{ mA}) / h_{FE} (I_C = 2\text{ mA}) = 0.95$ (Typ.)
- High h_{FE} : $h_{FE} = 120 \sim 400$
- Complementary to 2SA1832F
- Small Package

MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V_{CBO}	60	V
Collector-Emitter Voltage	V_{CEO}	50	V
Emitter-Base Voltage	V_{EBO}	5	V
Collector Current	I_C	150	mA
Base Current	I_B	30	mA
Collector Power Dissipation	P_C	100	mW
Junction Temperature	T_j	125	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	$-55 \sim 125$	$^\circ\text{C}$

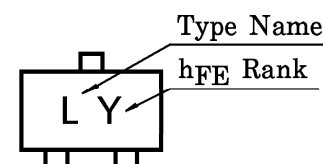
ELECTRICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I_{CBO}	$V_{CB} = 60\text{ V}$, $I_E = 0$	—	—	0.1	μA
Emitter Cut-off Current	I_{EBO}	$V_{EB} = 5\text{ V}$, $I_C = 0$	—	—	0.1	μA
DC Current Gain	h_{FE} (Note)	$V_{CE} = 6\text{ V}$, $I_B = 2\text{ mA}$	120	—	400	
Collector-Emitter Saturation Voltage	$V_{CE}(\text{sat})$	$I_C = 100\text{ mA}$, $I_B = 10\text{ mA}$	—	0.1	0.25	V
Transition Frequency	f_T	$V_{CE} = 10\text{ V}$, $I_C = 1\text{ mA}$	80	—	—	MHz
Collector Output Capacitance	C_{ob}	$V_{CB} = 10\text{ V}$, $I_E = 0$, $f = 1\text{ MHz}$	—	2.0	3.5	pF

(Note) : h_{FE} Classification Y (Y) : 120~240, GR (G) : 200~400

() Marking Symbol

MARKING



961001EAA1

- TOSHIBA is continually working to improve the quality and the reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to observe standards of safety, and to avoid situations in which a malfunction or failure of a TOSHIBA product could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent products specifications. Also, please keep in mind the precautions and conditions set forth in the TOSHIBA Semiconductor Reliability Handbook.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.

